



MJD31CH

**100V NPN MEDIUM POWER TRANSISTOR IN TO252** 

#### Features

- BV<sub>CEO</sub> > 100V
- I<sub>C</sub> = 3A Continuous Collector Current
- I<sub>CM</sub> = 5A Peak Pulse Current
- Ideal for Power Switching or Amplification Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An automotive-compliant part is available under separate datasheet (MJD31CHQ)

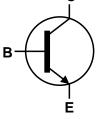
#### **Mechanical Data**

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.34 grams (Approximate)



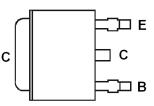
TO252 (DPAK)

Top View



С

**Device Schematic** 



Pin Out Configuration Top View

#### Ordering Information (Note 4)

Part Number Package Marking Reel Size (inches) Tape Width (mm)						king
Part Number	Package	Marking	Reel Size (Inches)	rape width (mm)	Qty.	Carrier
MJD31CH-13	TO252 (DPAK)	MJD31CH	13	16	2500	Reel

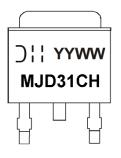
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



MJD31CH = Product Type Marking Code )!! = Manufacturers' Code Marking YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 24 = 2024) WW = Week Code (01 to 53)



#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vcbo	120	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage	VEBO	7	V
Continuous Collector Current	lc	3	A
Peak Pulse Collector Current	Ісм	5	A
Continuous Base Current	Ів	1	A

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		2.60		
Power Dissipation	(Note 6)	PD	2.30	W	
	(Note 7)		1.45		
	(Note 5)		48		
Thermal Resistance, Junction to Ambient Air	(Note 6)	R <sub>0JA</sub>	54	°C/W	
	(Note 7)	1	86		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	O°	

## ESD Ratings (Note 8)

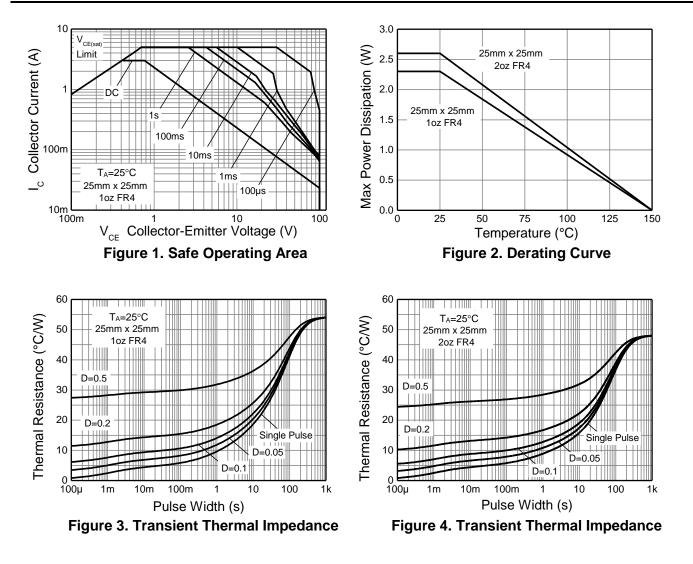
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

5. For a device mounted with the exposed collector pad on 25mm × 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady state.
6. Same as note (5), except mounted on 25mm × 25mm 1oz copper. Notes:

7. Same as note (5), except mounted on minimum recommended pad (MRP) layout. 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics**



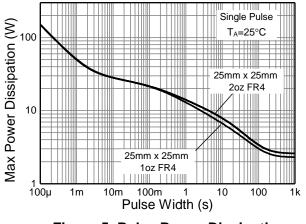


Figure 5. Pulse Power Dissipation



## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

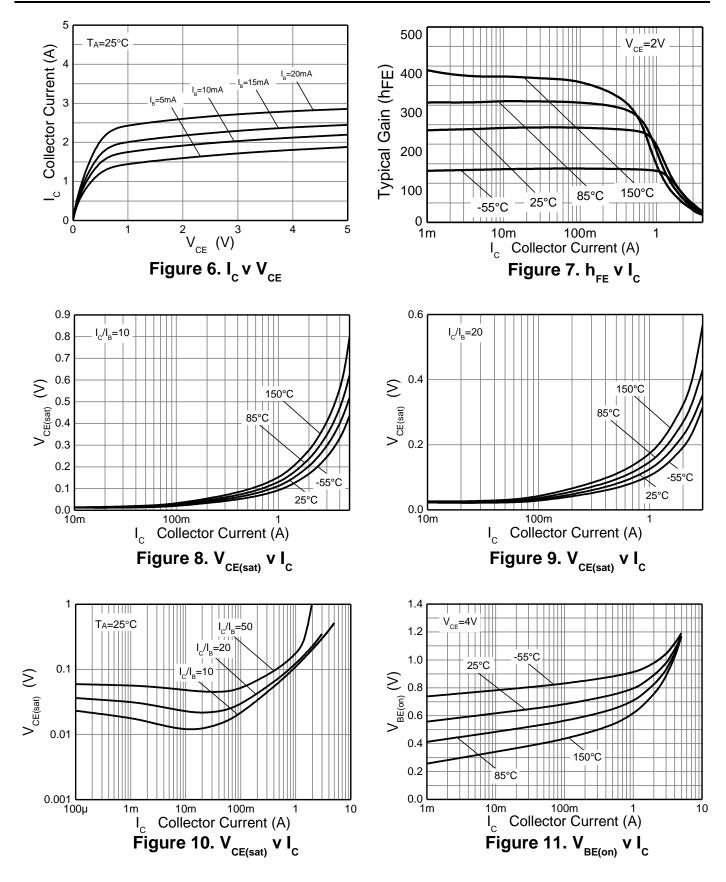
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	120		_	V	Ic = 100µA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	100		—	V	$I_{C} = 10 \text{mA}$
Emitter-Base Breakdown Voltage	BVEBO	7	_	—	V	I <sub>E</sub> = 100μA
Collector Cut-Off Current	ICES	_	_	1	μA	$V_{CE} = 100V$
Collector-Base Cut-Off Current	I <sub>CBO</sub>	—	_	100	nA	$V_{CB} = 100V$
Emitter Cut-Off Current	IEBO	—		1	μA	V <sub>EB</sub> = 6V
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)	—	_	1.2	V	Ic = 3A, I <sub>B</sub> = 375mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	_	_	1.35	V	I <sub>C</sub> = 3A, I <sub>B</sub> = 375mA
Base-Emitter Turn-On Voltage (Note 9)	VBE(on)	_	_	1.8	V	IC = 3A, VCE = 4V
		120	_	_		Vce = 60V, Ic = 20mA
DC Current Gain (Note 9)	hfe	100	—	—		$V_{CE} = 4V, I_{C} = 0.5A$
	UFE	25	—	—		$V_{CE} = 4V, I_C = 1A$
		10	_	_		$V_{CE} = 4V, I_C = 3A$
Small Signal Current Gain	h <sub>fe</sub>	20	_	—	—	Vce = 10V, Ic = 0.5A, f = 1kHz
Current Gain-Bandwidth Product	f⊤	3	_	—	MHz	Vce = 10V, Ic = 0.5A, f = 100MHz
Output Capacitance	Cobo	—	15	_	pF	$V_{CB} = 10V, f = 1MHz$
Input Capacitance	Cibo	_	310	_	pF	V <sub>EB</sub> = 0.5V, f = 1MHz
Delay Time	td	_	30	—	ns	
Rise Time	tr	_	20	_	ns	Ic = 0.5A, Vcc = 10V,
Storage Time	ts	_	430	_	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$
Fall Time	tf		80	_	ns	]

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



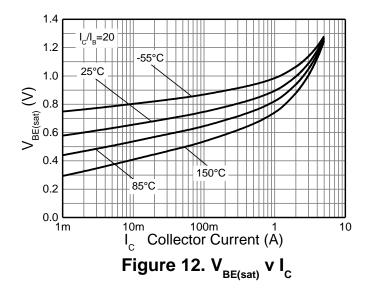
MJD31CH

# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





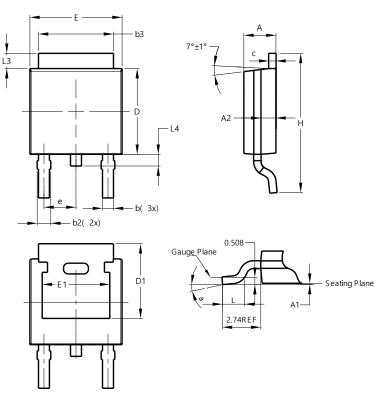
# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.) (continued)





## **Package Outline Dimensions**

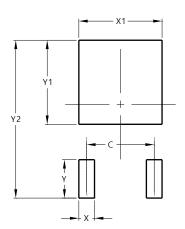
Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.50	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21				
е	2.286 BSC				
Е	6.45	6.70	6.58		
E1	4.32				
Η	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°			
All	All Dimensions in mm				

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252	(DPAK)

Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700



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